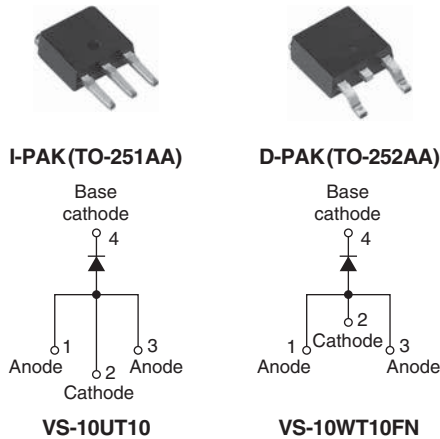


## High Performance Generation 5.0 Schottky Rectifier, 10 A



### FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized  $V_F$  vs.  $I_R$  trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47


**RoHS**  
COMPLIANT

PRODUCT SUMMARY	
Package	I-PAK (TO-251AA), D-PAK (TO-252AA)
$I_{F(AV)}$	10 A
$V_R$	100 V
$V_F$ at $I_F$	0.66 V
$I_{RM}$ max.	4 mA at 125 °C
$T_J$ max.	175 °C
Diode variation	Single die
$E_{AS}$	54 mJ

### APPLICATIONS

- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$V_{RRM}$		100	V
$V_F$	10 Apk, $T_J = 125$ °C (typical)	0.615	V
$T_J$	Range	- 55 to 175	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-10UT10 VS-10WT10FN	UNITS
Maximum DC reverse voltage	$V_R$	$T_J = 25$ °C	100	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 159$ °C, rectangular waveform		10	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu$ s sine or 3 $\mu$ s rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied (1)	610	A
		10 ms sine or 6 ms rect. pulse		110	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25$ °C, $I_{AS} = 3$ A, $L = 12$ mH		54	mJ
Repetitive avalanche current	$I_{AR}$	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. $I_{AS}$ at $T_J$ max. as a function of time pulse (see fig. 8)		$I_{AS}$ at $T_J$ max.	A

#### Note

(1) Measured connecting 2 anode pins



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS	
Forward voltage drop	$V_{FM}^{(1)(2)}$	5 A	0.630	-	V	
		10 A				$T_J = 25\text{ }^\circ\text{C}$
		20 A				
		5 A	0.530	-		
		10 A				$T_J = 125\text{ }^\circ\text{C}$
		20 A				
20 A	0.730	0.770				
Reverse leakage current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	-	50	$\mu\text{A}$	
		$T_J = 125\text{ }^\circ\text{C}$	-	4	mA	
Junction capacitance	$C_T$	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$	400	-	pF	
Series inductance	$L_S$	Measured lead to lead 5 mm from package body	8.0	-	nH	
Maximum voltage rate of change	dV/dt	Rated $V_R$	-	10 000	V/ $\mu\text{s}$	

**Notes**

- (1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2 %
- (2) Only 1 anode pin connected

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	2	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	$R_{thCS}$		0.3	
Approximate weight			0.3	g
			0.01	oz.
Marking device		Case style I-PAK	10UT10	
		Case style D-PAK	10WT10FN	

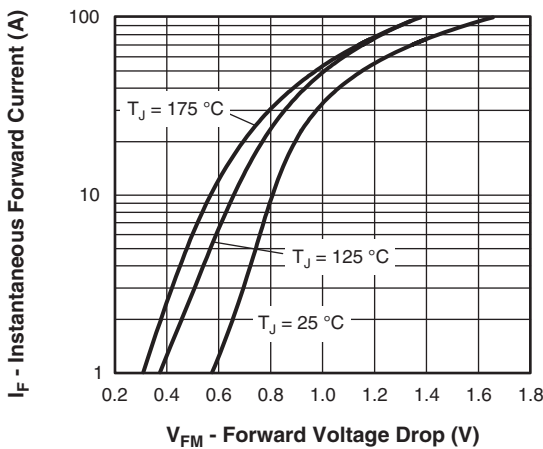


Fig. 1 - Maximum Forward Voltage Drop Characteristics

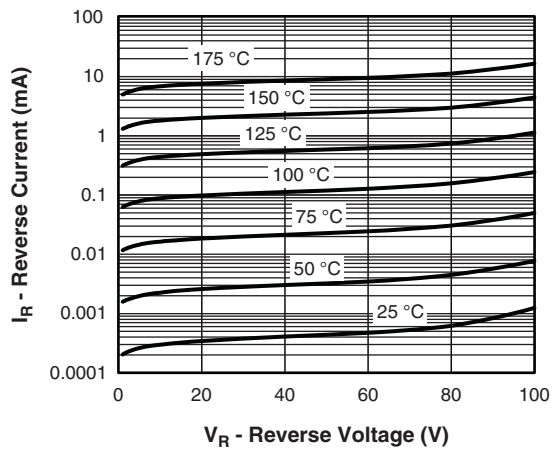


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

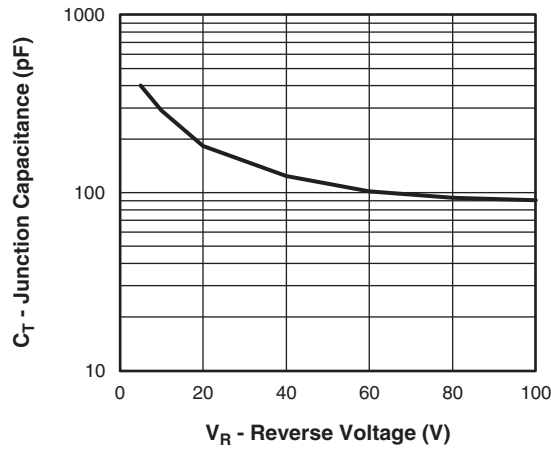


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

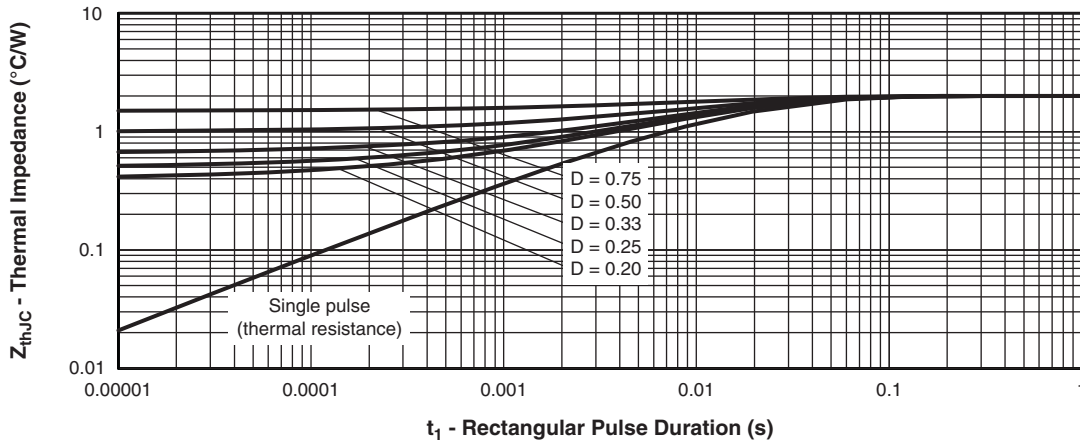


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

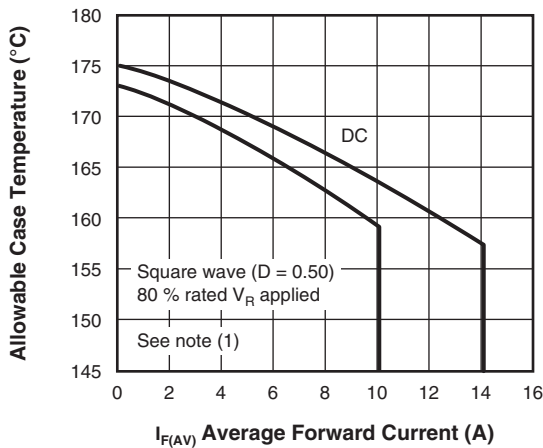


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

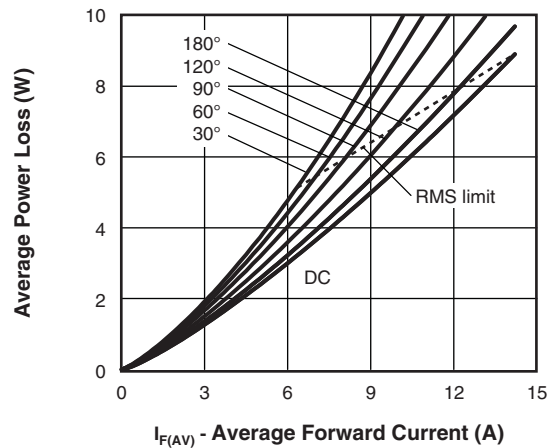


Fig. 6 - Forward Power Loss Characteristics

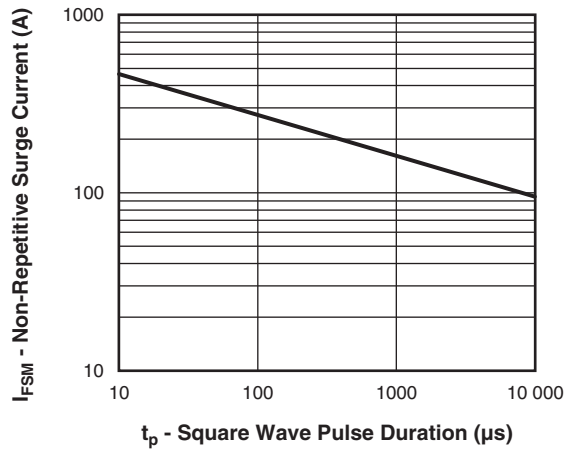


Fig. 7 - Maximum Non-Repetitive Surge Current

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;
- $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $P_{d_{REV}}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

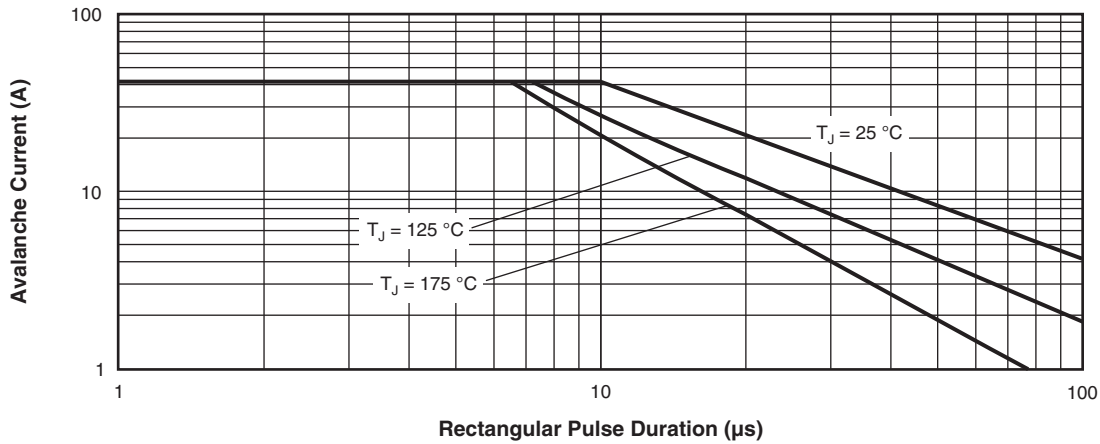


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

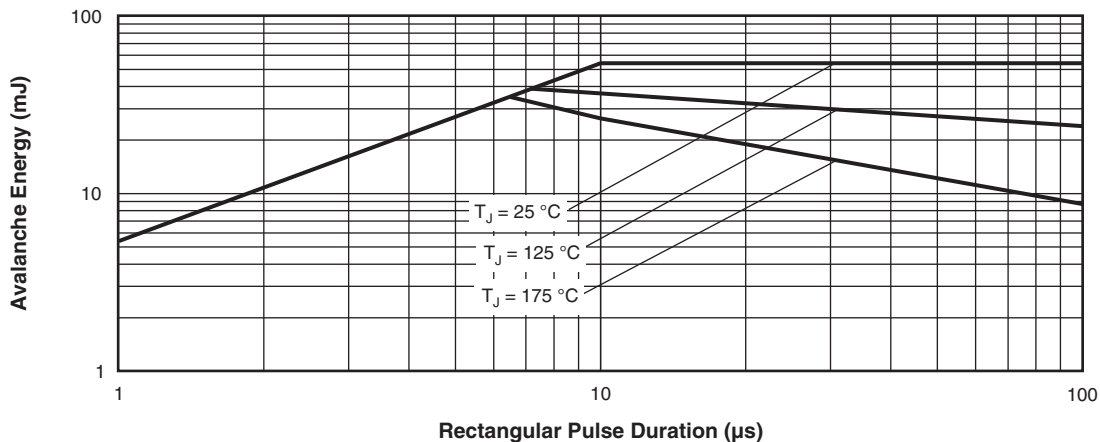
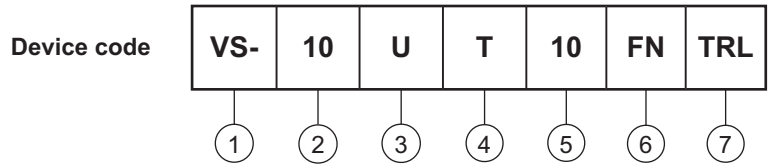


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



## ORDERING INFORMATION TABLE

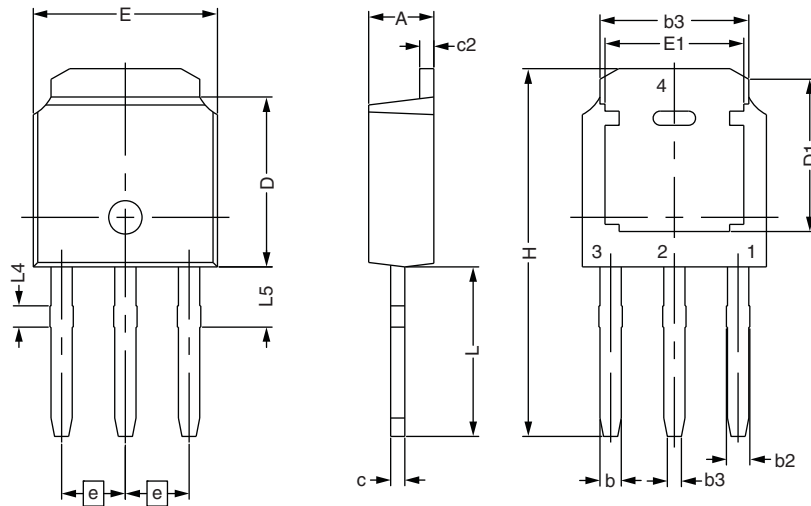


- 1** - Vishay Semiconductors product
- 2** - Current rating (10 A)
- 3** - Package:
  - U = I-PAK
  - W = D-PAK
- 4** - T = Trench
- 5** - Voltage code (100 V)
- 6** - TO-252AA (D-PAK)
- 7** - D-PAK, I-PAK:
  - None = Tube (75 pieces)
  - D-PAK only:
    - TR = Tape and reel
    - TRL = Tape and reel (left oriented)
    - TRR = Tape and reel (right oriented)

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95024">www.vishay.com/doc?95024</a>
Part marking information	<a href="http://www.vishay.com/doc?95025">www.vishay.com/doc?95025</a>
Packaging information	<a href="http://www.vishay.com/doc?95033">www.vishay.com/doc?95033</a>
SPIICE model	<a href="http://www.vishay.com/doc?95026">www.vishay.com/doc?95026</a>

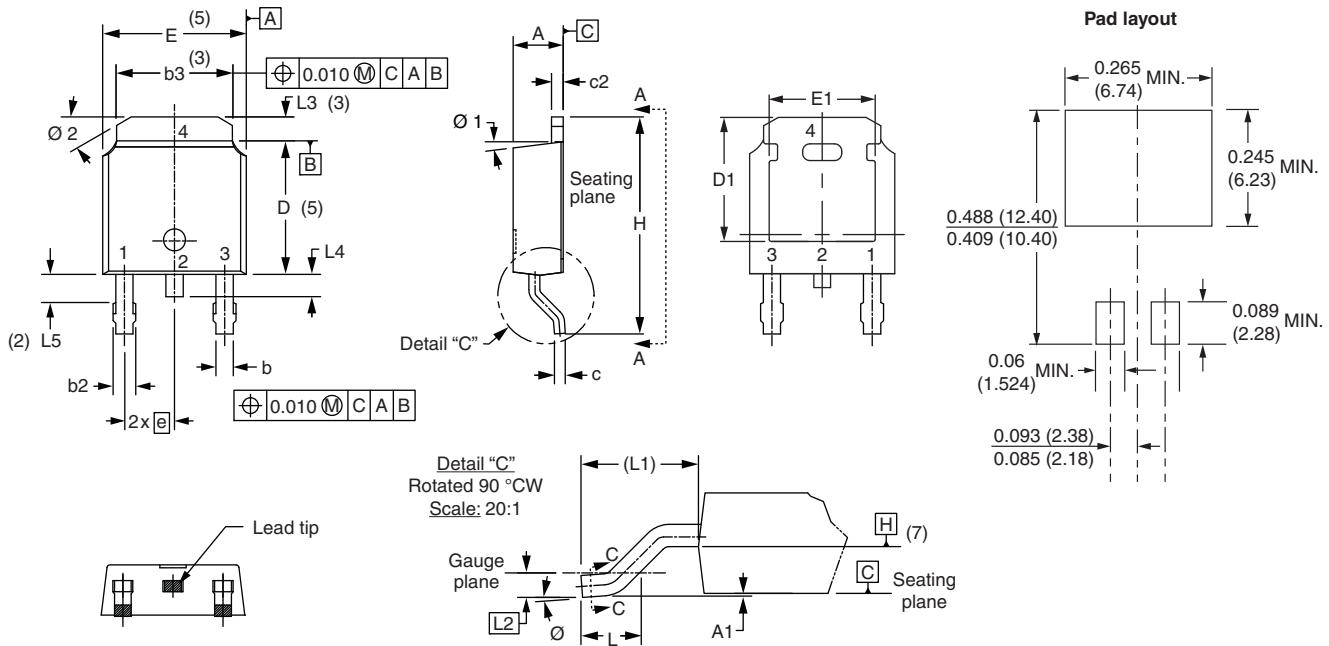
## I-PAK - S, D-PAK

### DIMENSIONS FOR I-PAK - S in millimeters



SYMBOL	DIMENSIONAL REQUIREMENTS		
	MIN.	NOM.	MAX.
E	6.40	6.60	6.70
L	3.98	4.13	4.28
L4	0.66	0.76	0.86
L5	1.96	2.16	2.36
D	6.00	6.10	6.20
H	11.05	11.25	11.45
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
b4	0.41	0.51	0.61
e	2.286 BSC		
A	2.20	2.30	2.38
c	0.40	0.50	0.60
c2	0.40	0.50	0.60
D1	5.30	-	-
E1	4.40	-	-

## DIMENSIONS FOR D-PAK in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	2.18	2.39	0.086	0.094		e	2.29 BSC		0.090 BSC		
A1	-	0.13	-	0.005		H	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035		L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045		L1	2.74 BSC		0.108 REF.		
b3	4.95	5.46	0.195	0.215	3	L2	0.51 BSC		0.020 BSC		
c	0.46	0.61	0.018	0.024		L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035		L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3	Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3	Ø2	25°	35°	25°	35°	

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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